

# Dressed Graphene Model

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This thesis concerned with a specific model. Idea: Graphene with an added orbital on one of the lattice site with a low hopping, as to provide a flat band. I will call this model dressed Graphene from here on. This chapter reviews the lattice structure in section 1.1.

## 1.1 Lattice Structure

There exist a few different ways to define the lattice structure of Graphene which are all equivalent, but intermediate steps in calculating tight-binding models look different depending on the definition. This review on follows ref. [1].

Monolayer graphene forms a honeycomb lattice, which is a hexagonal Bravais lattice with a two atom basis, as can be seen in fig. 1.1a. The primitive lattice vectors of the hexagonal lattice are:

$$\mathbf{a}_1 = \frac{a}{2} \begin{pmatrix} 1 \\ \sqrt{3} \end{pmatrix}, \quad \mathbf{a}_2 = \frac{a}{2} \begin{pmatrix} 1 \\ -\sqrt{3} \end{pmatrix} \quad (1.1)$$

with lattice constant  $a = \sqrt{3}a_0 \approx 2.46 \text{ \AA}$ , using the nearest-neighbour distance  $a_0$ . The vectors to the nearest-neighbor atoms  $B_i$  ( $i = 1, 2, 3$ ) from atom  $A$  are and the vectors to the nearest-neighbor atoms  $A_i$  ( $i = 1, 2, 3$ ) from atom  $B$  are The vectors between the Graphene  $A$  atom and the six neighbours on the same sub lattice are:

$$\delta_{AA,1} = \begin{pmatrix} 1 \\ \sqrt{3} \end{pmatrix}, \quad \delta_{AA,2} = a \begin{pmatrix} 1 \\ 0 \end{pmatrix}, \quad \delta_{AA,3} = a \begin{pmatrix} \frac{1}{2} \\ -\frac{\sqrt{3}}{2} \end{pmatrix}, \quad (1.2)$$

$$\delta_{AA,4} = a \begin{pmatrix} -\frac{1}{2} \\ -\frac{\sqrt{3}}{2} \end{pmatrix}, \quad \delta_{AA,5} = a \begin{pmatrix} -1 \\ 0 \end{pmatrix}, \quad \delta_{AA,6} = a \begin{pmatrix} -\frac{1}{2} \\ \frac{\sqrt{3}}{2} \end{pmatrix} \quad (1.3)$$

The primitive reciprocal lattice vectors  $\mathbf{b}_1, \mathbf{b}_2$  fulfill

Write introduction to the model and what is done in this chapter

Connection with Niklas/Si-heon paper on dressed Graphene

Labels on vectors

labels on vectors

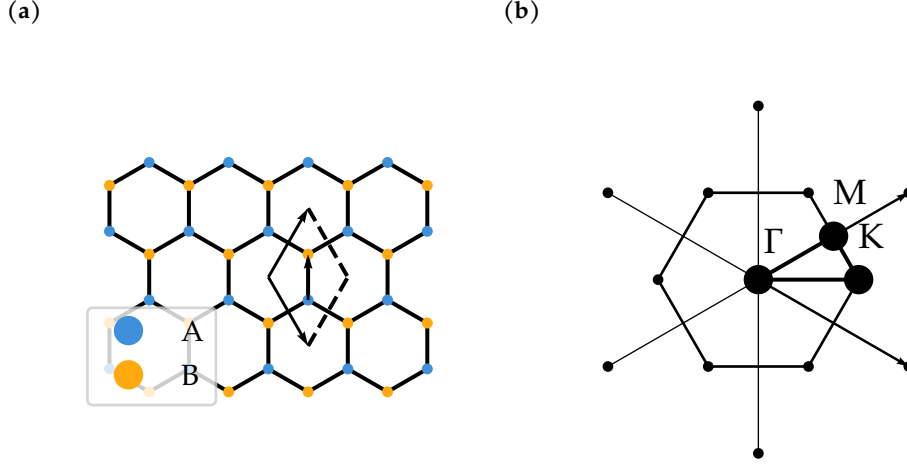


Figure 1.1 – (a) Graphene lattice structure and (b) Brilluoin zone

$$\mathbf{a}_1 \cdot \mathbf{b}_1 = \mathbf{a}_2 \cdot \mathbf{b}_2 = 2\pi \quad (1.4)$$

$$\mathbf{a}_1 \cdot \mathbf{b}_2 = \mathbf{a}_2 \cdot \mathbf{b}_1 = 0, \quad (1.5)$$

so we have:

$$\mathbf{b}_1 = \frac{2\pi}{a} \begin{pmatrix} 1 \\ \frac{1}{\sqrt{3}} \end{pmatrix}, \quad \mathbf{b}_2 = \frac{2\pi}{a} \begin{pmatrix} 1 \\ -\frac{1}{\sqrt{3}} \end{pmatrix} \quad (1.6)$$

The first Brilluoin zone of the hexagonal lattice is shown in fig. 1.1b, with the points of high symmetry

$$\Gamma = \begin{pmatrix} 0 \\ 0 \end{pmatrix}, \quad M = \frac{\pi}{a} \begin{pmatrix} 1 \\ \frac{1}{\sqrt{3}} \end{pmatrix}, \quad K = \frac{4\pi}{3a} \begin{pmatrix} 1 \\ 0 \end{pmatrix}. \quad (1.7)$$

## 1.2 Dressed Graphene Model

The model I am concerned with in this thesis consists of a Hubbard Hamiltonian (as introduced in ??) on a Graphene lattice, with one additional atom at one

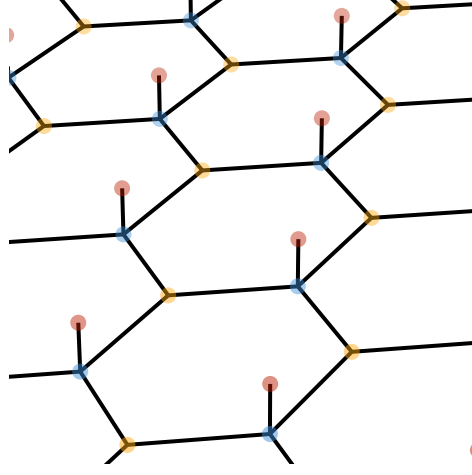


Figure 1.2 – Dressed Graphene model

of the two sites in a unit cell, which I will call X. This is shown in fig. 1.2. The kinetic term is

$$H_0 = -t_X \sum_{\langle ij \rangle, \sigma} d_{i, \sigma}^\dagger d_{j, \sigma} - t_{Gr} \sum_{\langle ij \rangle, \sigma} c_{i, \sigma}^{(A), \dagger} c_{j, \sigma}^{(B)} + V \sum_{i, \sigma \sigma'} d_{i, \sigma}^\dagger c_{i, \sigma'}^{(A)} + \text{h.c.} \quad (1.8)$$

Work over  
image for  
dressed  
graphene  
lattice

with

- $d$  - operators on the X atom
- $c^{(\epsilon)}$  - operators on the graphene sites ( $\epsilon = A, B$ )
- $t_X$  - nearest neighbour hopping for X
- $t_{Gr}$  - nearest neighbour hopping between Graphene sites
- $V$  - hopping between X and Graphene A sites.

The (attractive) Hubbard interaction has the following form:

$$H_{\text{int}} = -U_X \sum_i d_{i, \uparrow}^\dagger d_{i, \downarrow}^\dagger d_{i, \downarrow} d_{i, \uparrow} - U_{Gr} \sum_{i, \epsilon=A, B} c_{i, \uparrow}^{(\epsilon), \dagger} c_{i, \downarrow}^{(\epsilon), \dagger} c_{i, \downarrow}^{(\epsilon)} c_{i, \uparrow}^{(\epsilon)} \quad (1.9)$$

The notation using different letters for the sites connects intuitively to the physical picture, but it is more economical and in line with the notation for

mean field-theory established in ?? to write the Hamiltonian using a sublattice index

$$\alpha = 1, 2, 3 \quad (1.10)$$

with  $1 \cong \text{Gr}_A$ ,  $2 \cong \text{Gr}_B$ ,  $3 \cong X$ . Then we can write the non-interacting term as

$$H_0 = \sum_{\langle i,j \rangle, \alpha, \beta, \sigma} [\mathbf{t}]_{i\alpha, j\beta} c_{i\alpha}^\dagger c_{j\beta} \quad (1.11)$$

with the matrix in the sublattice indices

$$\mathbf{t} = \begin{pmatrix} 0 & -t_{\text{Gr}} & V\delta_{ij} \\ -t_{\text{Gr}} & 0 & 0 \\ V\delta_{ij} & 0 & -t_X \end{pmatrix} \quad (1.12)$$

Also write the interaction part as

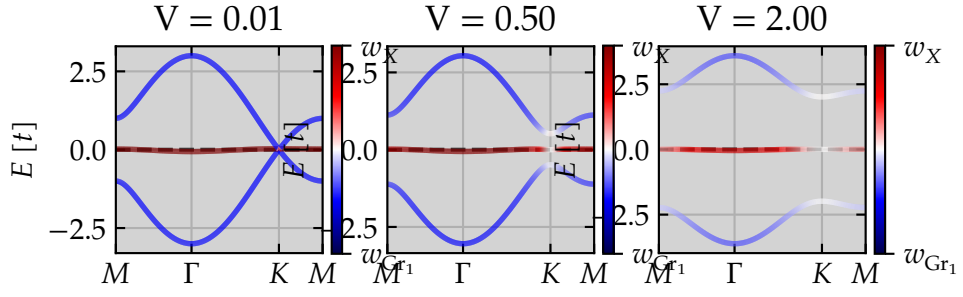
$$H_{\text{int}} = - \sum_{i\alpha} U_\alpha c_{i\alpha\uparrow}^\dagger c_{i\alpha\downarrow}^\dagger c_{i\alpha\downarrow} c_{i\alpha\uparrow} . \quad (1.13)$$

Using the Fourier transformation ??

$$H_0 = \sum_{\mathbf{k}, \sigma, \sigma'} \begin{pmatrix} c_{\mathbf{k}, \sigma}^{A, \dagger} & c_{\mathbf{k}, \sigma}^{B, \dagger} & d_{\mathbf{k}, \sigma}^\dagger \end{pmatrix} \begin{pmatrix} 0 & f_{\text{Gr}} & V \\ f_{\text{Gr}}^* & 0 & 0 \\ V & 0 & f_X \end{pmatrix} \begin{pmatrix} c_{\mathbf{k}, \sigma}^A \\ c_{\mathbf{k}, \sigma}^B \\ d_{\mathbf{k}, \sigma} \end{pmatrix} \quad (1.14)$$

Clean up the section from here

The band structure for the non-interacting dressed graphene model is easily obtained by diagonalising the matrix in eq. (1.14). This was done in fig. 1.3.



**Figure 1.3** – Bands of the non-interacting dressed Graphene model, with parameters  $t_X = 0 \cdot t_{Gr}$